C4D08120E

Silicon Carbide Schottky Diode

Z-Rec® Rectifier

V_{RRM}	=	1200 V
I_F (T_C=135°C)	=	12 A
Q_c	=	37 nC

Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Solar Inverters
- UPS
- Motor Drives
- Power Factor Correction

Package



TO-252-2

Halogen-Free

RoHS



Part Number	Package	Marking
C4D08120E	TO-252-2	C4D08120

Maximum Ratings (T_C=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V		
V_{RSM}	Surge Peak Reverse Voltage	1300	V		
V_{DC}	DC Blocking Voltage	1200	V		
I_F	Continuous Forward Current	24.5 12 8	A	T_C=25°C T_C=135°C T_C=155°C	
I_{FRM}	Repetitive Peak Forward Surge Current	38 26	A	T_C=25°C, t_P=10 ms, Half Sine pulse T_C=110°C, t_P=10 ms, Half Sine pulse	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	64 50	A	T_C=25°C, t_P=10 ms, Half Sine pulse T_C=110°C, t_P=10 ms, Half Sine pulse	
$I_{F,Max}$	Non-Repetitive Peak Forward Current	600 480	A	T_C=25°C, t_P=10 µs, Pulse T_C=110°C, t_P=10 µs, Pulse	
P_{tot}	Power Dissipation	137 59	W	T_C=25°C T_C=110°C	
T_J	Operating Junction Range	-55 to +175	°C		
T_{stg}	Storage Temperature Range	-55 to +135	°C		

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.5 2.2	1.8 3	V	I_F = 2 A T_J=25°C I_F = 2 A T_J=175°C	
I_R	Reverse Current	35 100	250 350	μA	V_R = 1200 V T_J=25°C V_R = 1200 V T_J=175°C	
Q_C	Total Capacitive Charge	37		nC	V_R = 800 V, I_F = 2A di/dt = 200 A/μs T_J = 25°C	
C	Total Capacitance	560 37 27		pF	V_R = 0 V, T_J = 25°C, f = 1 MHz V_R = 400 V, T_J = 25°C, f = 1 MHz V_R = 800 V, T_J = 25°C, f = 1 MHz	

Note:
1. This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	TO-252 Package Thermal Resistance from Junction to Case	1.1	°C/W

Typical Performance

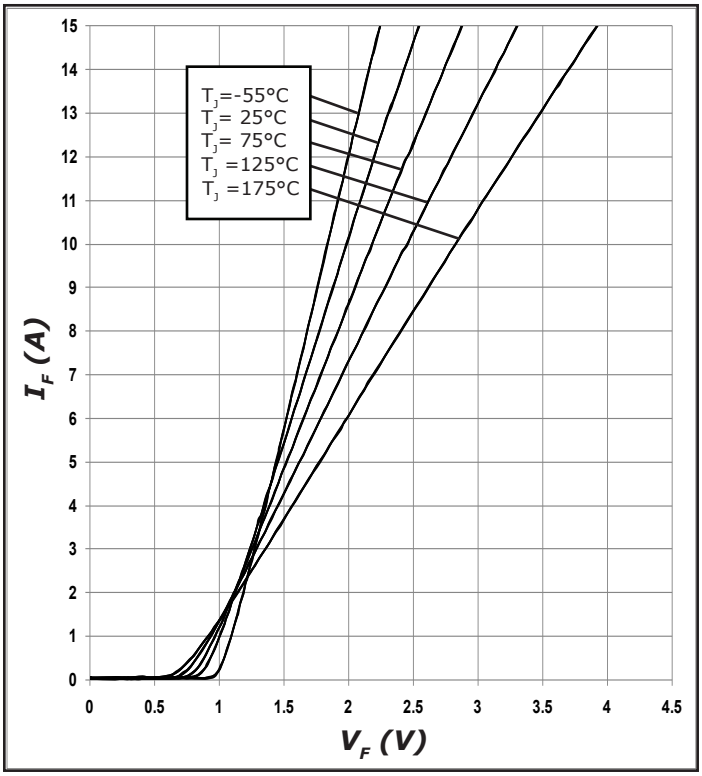


Figure 1. Forward Characteristics

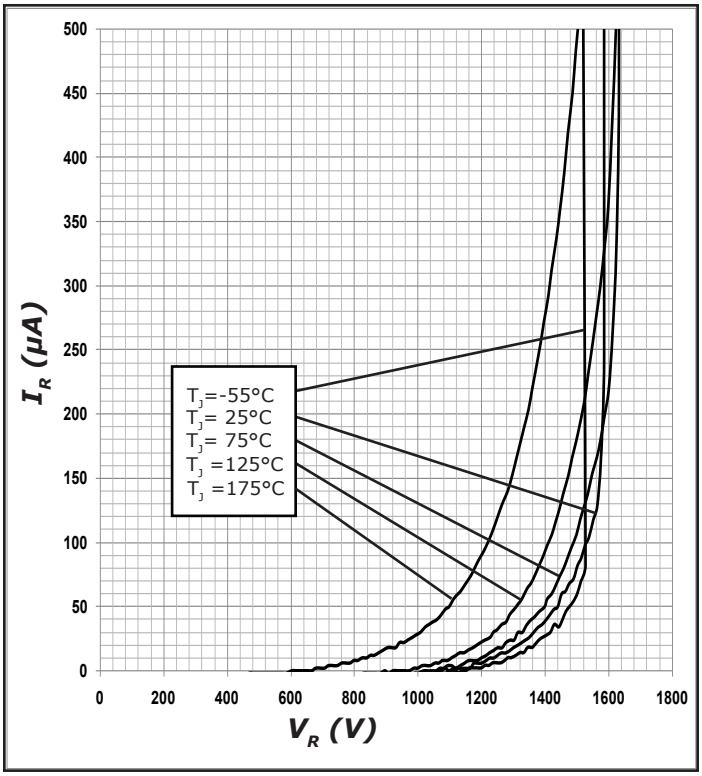


Figure 2. Reverse Characteristics

Typical Performance

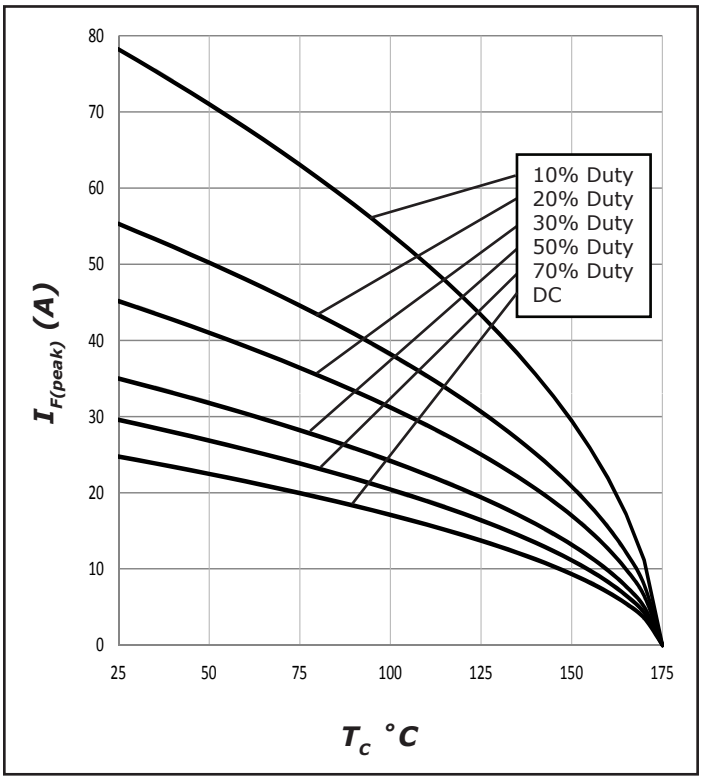


Figure 3. Current Derating

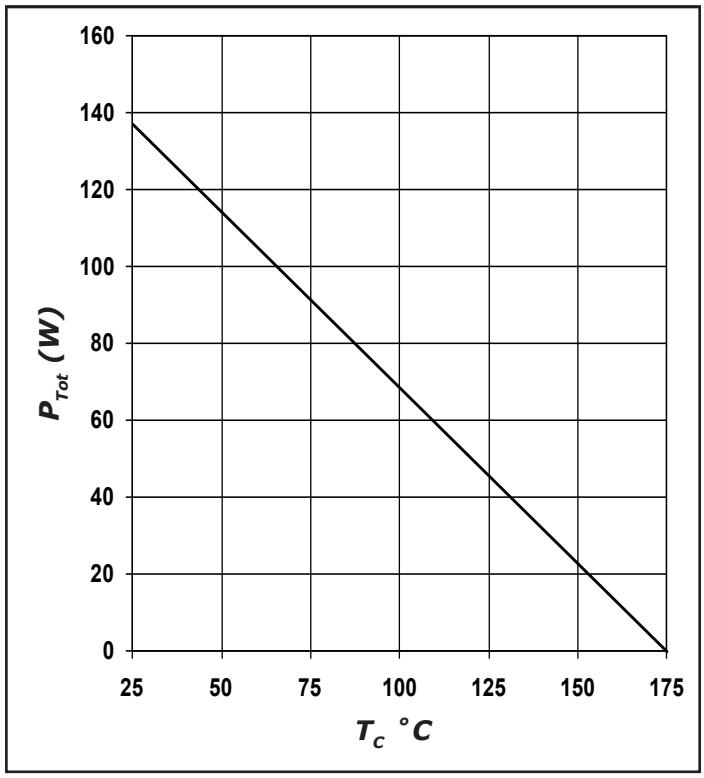


Figure 4. Power Derating

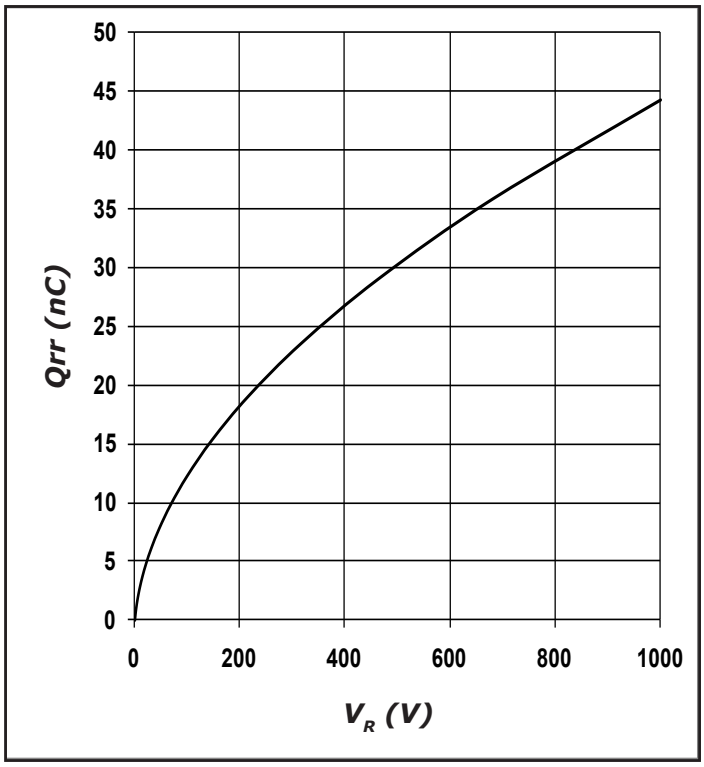


Figure 5. Recovery Charge vs. Reverse Voltage

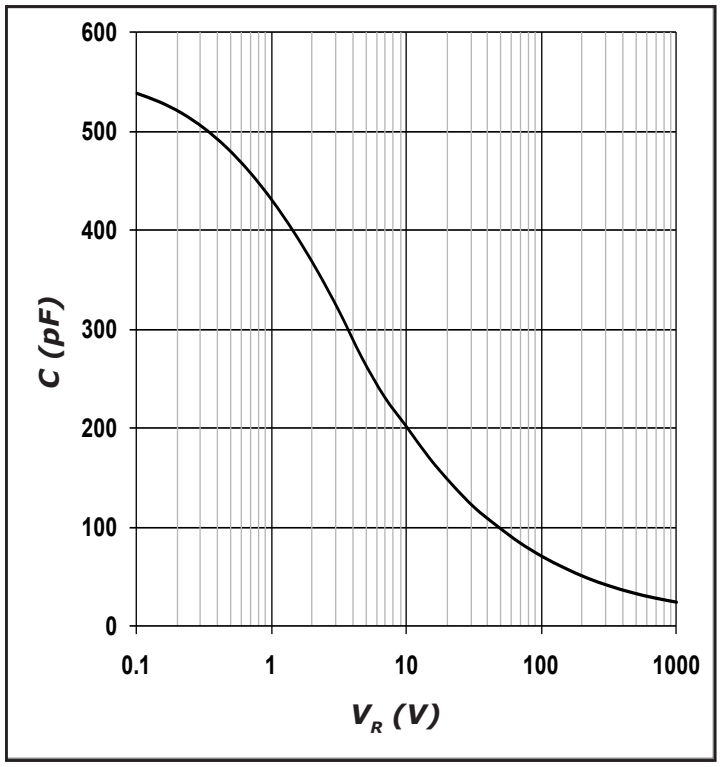


Figure 6. Capacitance vs. Reverse Voltage

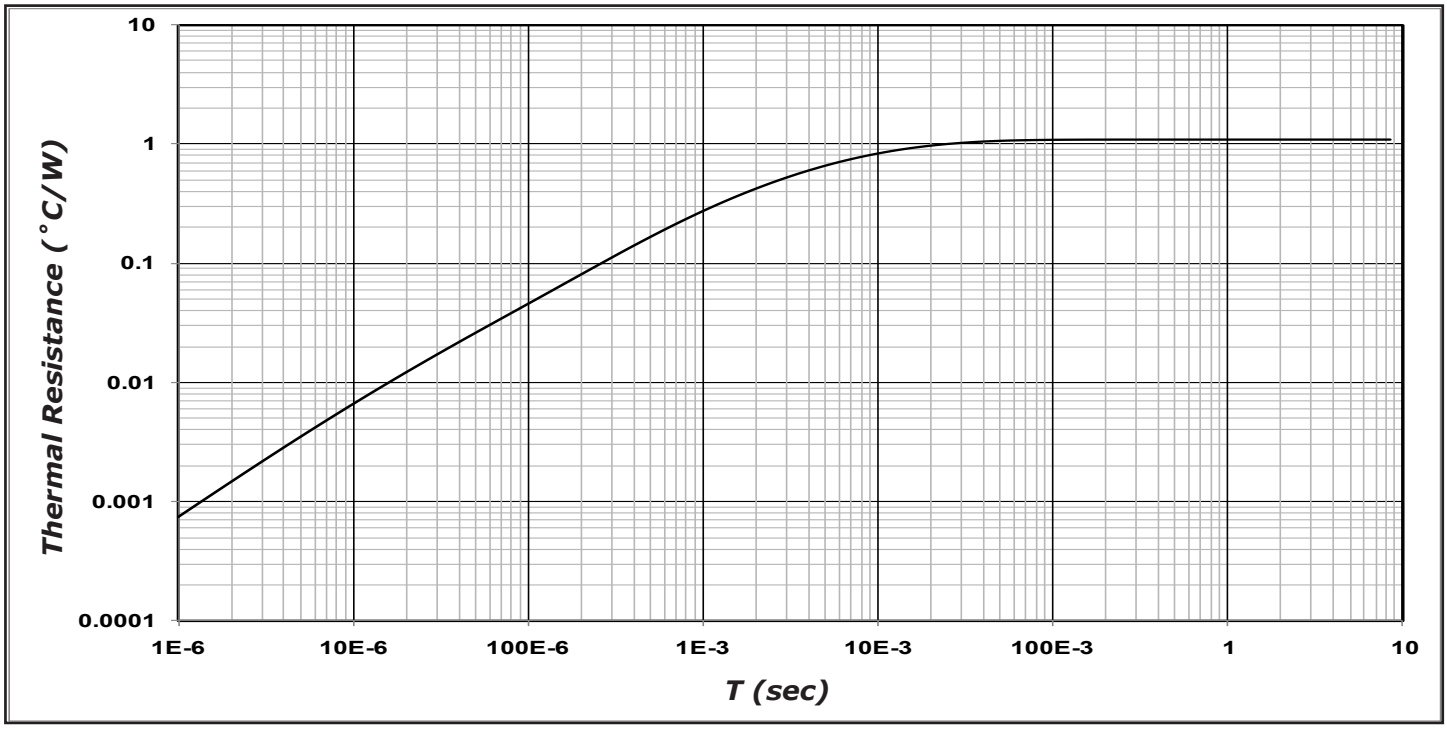
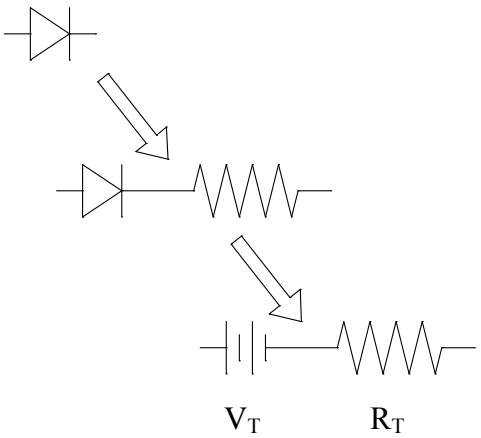


Figure 7. Transient Thermal Impedance

Diode Model



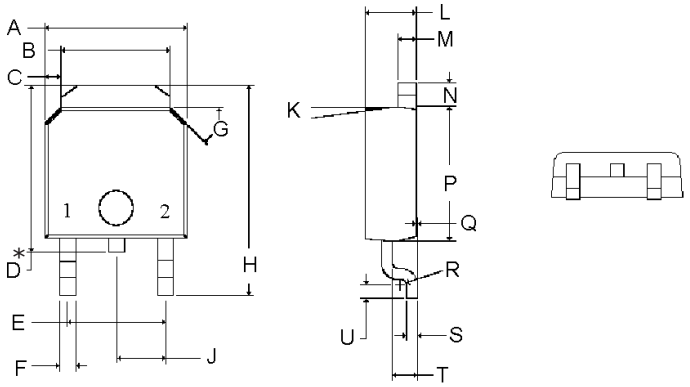
$$V_{fT} = V_T + If * R_T$$

$$V_T = 0.96 + (T_J * -2.1*10^{-3})$$
$$R_T = 0.06 + (T_J * 8.0*10^{-4})$$

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

Package Dimensions

Package TO-252-2

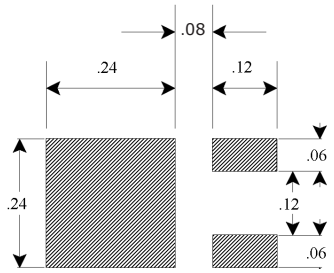




POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.250	.289	6.350	7.341
B	.197	.215	5.004	5.461
C	.027	.050	.686	1.270
D*	.270	.322	6.858	8.179
E	.178	.182	4.521	4.623
F	.025	.045	.635	1.143
G	44°	46°	44°	46°
H	.380	.410	9.652	10.414
J	.090 TYP		2.286 TYP	
K	6°	8°	6°	8°
L	.086	.094	2.184	2.388
M	.018	.034	.457	.864
N	.035	.050	.889	1.270
P	.231	.246	5.867	6.248
Q	0.00	.005	0.00	.127
R	R0.010 TYP		R0.254 TYP	
S	.017	.023	.432	.584
T	.038	.045	.965	1.143
U	.021	.029	.533	.737

Note:
* Tab "D" may not be present

Recommended Solder Pad Layout



TO-252-2

Part Number	Package	Marking
C4D05120E	TO-252-2	C4D05120

Note: Recommended soldering profiles can be found in the applications note here:
http://www.cree.com/power_app_notes/soldering

Notes

- **RoHS Compliance**
  The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Cree representative or from the Product Documentation sections of www.cree.com.

- **REACh Compliance**
  REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future,please contact a Cree representative to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

- This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

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